Analog Power

AM30N02-59D

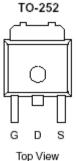
N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

- Low r_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature TO-252 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY				
V _{DS} (V)	r _{DS(on)} m(Ω)	I _D (A)		
2.0	$59 @ V_{GS} = 4.5V$	24		
20	$88 @ V_{GS} = 2.5V$	20		





Parameter			Limit	Units
Drain-Source Voltage		V _{DS}	20	v
Gate-Source Voltage		V _{GS}	±12	v
Continuous Drain Current ^a	$T_{\rm C}=25^{\rm o}{\rm C}$	I _D	24	
Pulsed Drain Current ^b		I _{DM}	40	A
Continuous Source Current (Diode Conduction) ^a		Is	30	Α
Power Dissipation ^a	$T_{\rm C}=25^{\rm o}{\rm C}$	P _D	50	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	50	°C/W	
Maximum Junction-to-Case	$R_{\theta JC}$	3.0	°C/W	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

	Samples	Same al Tract Care d'étana	Limits			TLª4	
Parameter	Symbol Test Conditions		Min	Тур	Max	Unit	
Static	_						
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.7			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = 20 V$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 16 V, V_{GS} = 0 V$			1	uA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 16 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			25	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 4.5 V$	34			Α	
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 12 \text{ A}$			59	mΩ	
Drain-Source On-Resistance		$V_{GS} = 2.5 \text{ V}, I_D = 10 \text{ A}$			88		
Forward Tranconductance ^A	g _{fs}	$V_{DS} = 10 \text{ V}, I_D = 12 \text{ A}$		22		S	
Diode Forward Voltage	V _{SD}	$I_{\rm S} = 24$ A, $V_{\rm GS} = 0$ V		1.1		V	
Dynamic ^b					-		
Total Gate Charge	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$		7.5		nC	
Gate-Source Charge	Q _{gs}	$v_{DS} = 10 v, v_{GS} = 4.3 v,$ $I_D = 10 A$		0.6			
Gate-Drain Charge	Q _{gd}	$I_{\rm D} = 10$ A		1.0		1	
Turn-On Delay Time	t _{d(on)}			16			
Rise Time	t _r	V_{DD} = 10 V, R_L = 25 Ω , ID = 24 A,		5		nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 V$		23		ns	
Fall-Time	t _f			3		1	

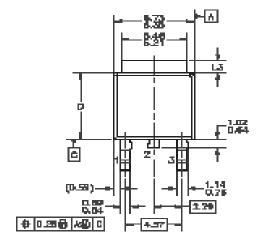
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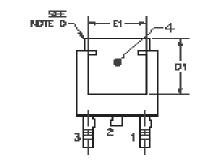
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

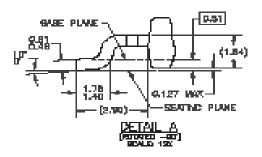
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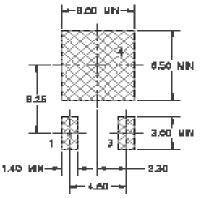
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Package Information

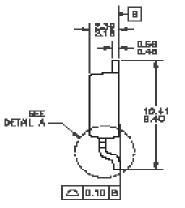








LAND PATTERN RECOMMENDATION



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